

Supporting Information

Photoelectrochemical OER activity by employing BiVO₄ with manganese oxide co-catalysts

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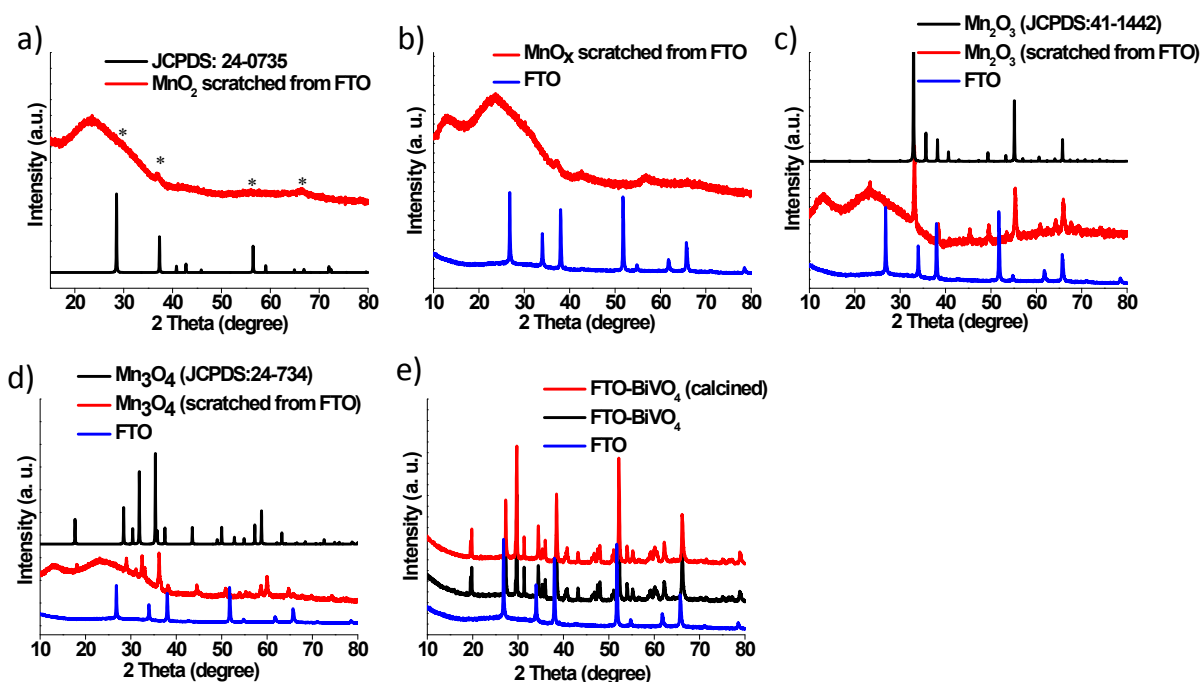


Fig. S1. Powder X-ray diffraction matched with ICDD files for a) MnO₂ b) MnO_x, for comparison FTO pattern is shown as the powder was deposited and scratched from FTO and highlights the absence of scratched SnO₂ c) Mn₂O₃ d) Mn₃O₄ e) FTO-BiVO₄ was heated at 600 °C and no change in the diffraction pattern was observed in comparison to the unannealed FTO-BiVO₄.

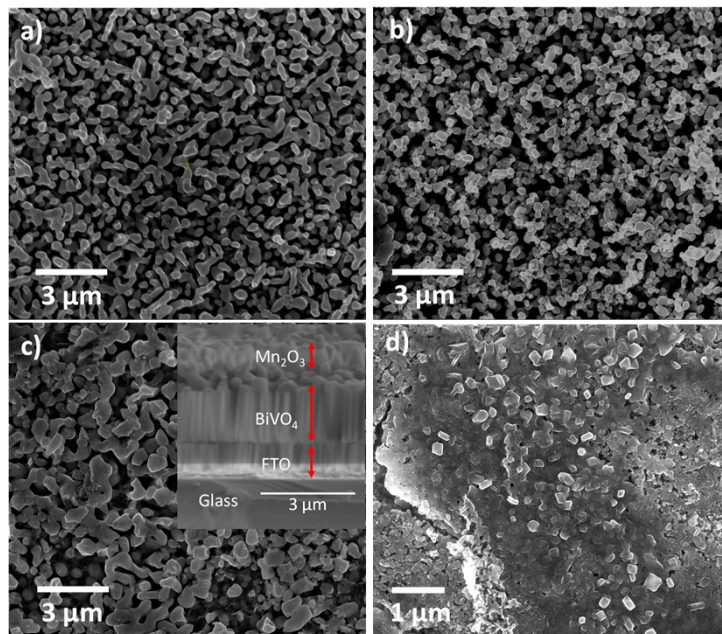


Fig. S2. FESEM top view of the electrode for a) FTO-BiVO₄ b) FTO-BiVO₄-MnO₂ c) FTO-BiVO₄-Mn₂O₃ (inset image showing cross-section of FTO-BiVO₄-Mn₂O₃ showing the electrodeposition of different layers d) FTO-BiVO₄-Mn₃O₄.

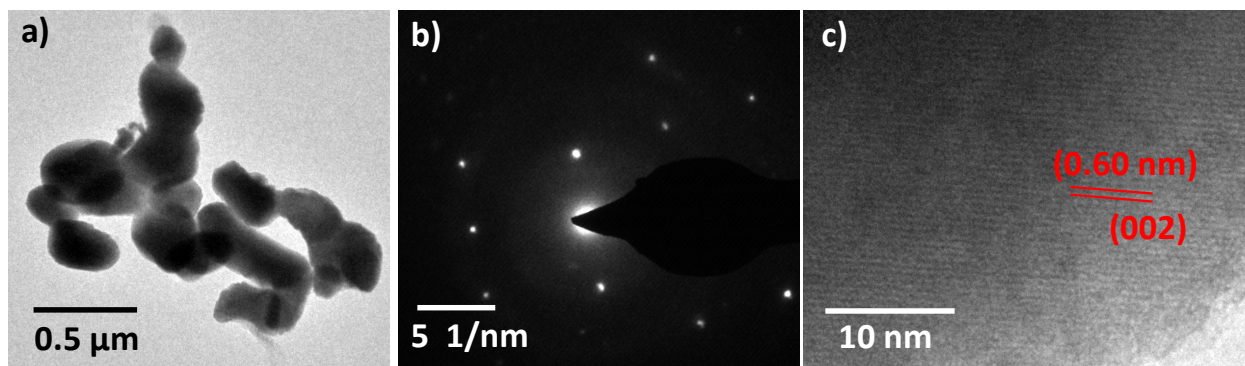


Fig. S3. a) TEM images for BiVO₄ scratched from FTO b) SAED pattern showing the crystalline nature of the BiVO₄ c) HRTEM image of BiVO₄ showing lattice fringe for the plane (002).

Note: Transmission electron microscopy (TEM) of BiVO₄ has shown the presence of particles of size range 0.5-1 μm. Small area electron diffraction (**Fig. S3b**) signifies the crystalline nature and HRTEM (**Fig. S3c**) reveals the presence of lattice fringes corresponding to the plane (002).

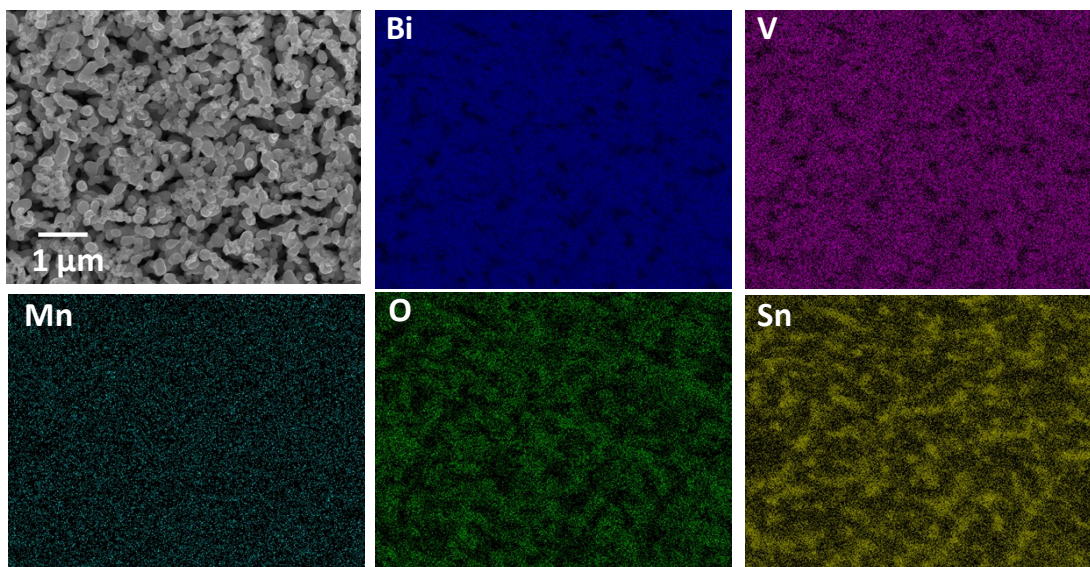


Fig. S4. Elemental mapping of top surface of FTO-BiVO₄-MnO_x showing uniform distribution of elements Bi, V, Sn, Mn, O and C.
 Note: Elemental mapping of top view of FTO-BiVO₄-MnO_x studies show has highlighted the uniform distribution of the Bi, V, Mn, O, C and Sn elements on the electrode surface.

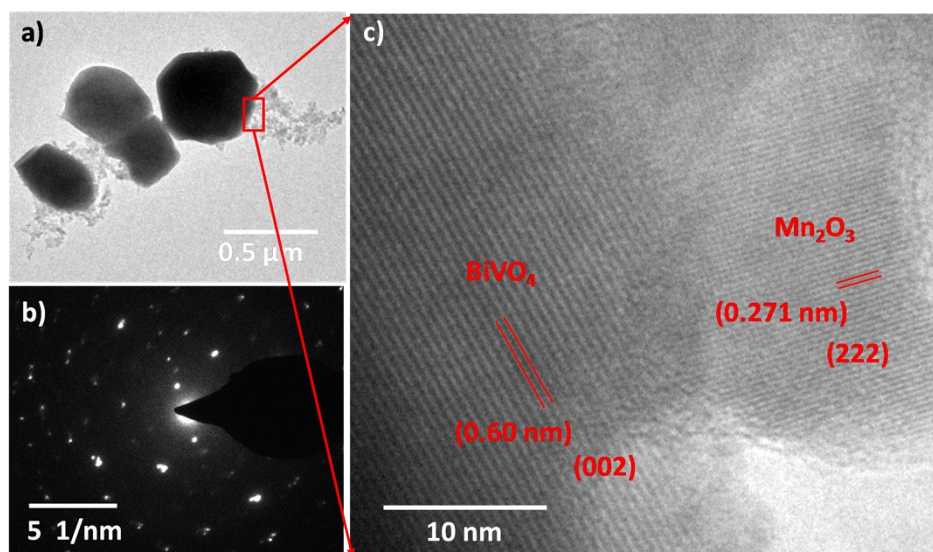


Fig S5. a) TEM images for BiVO₄-Mn₂O₃ scratched from FTO b) SAED pattern showing the crystalline nature of the BiVO₄ depicted by big spots and small spots correspond to Mn₂O₃ c) HRTEM image of BiVO₄ showing lattice fringe in close proximity of lattice fringe of Mn₂O₃ and their respective lattice fringes with interplanar spacing of 0.60 nm (002) and 0.27 nm (222) for BiVO₄ and Mn₂O₃ respectively.

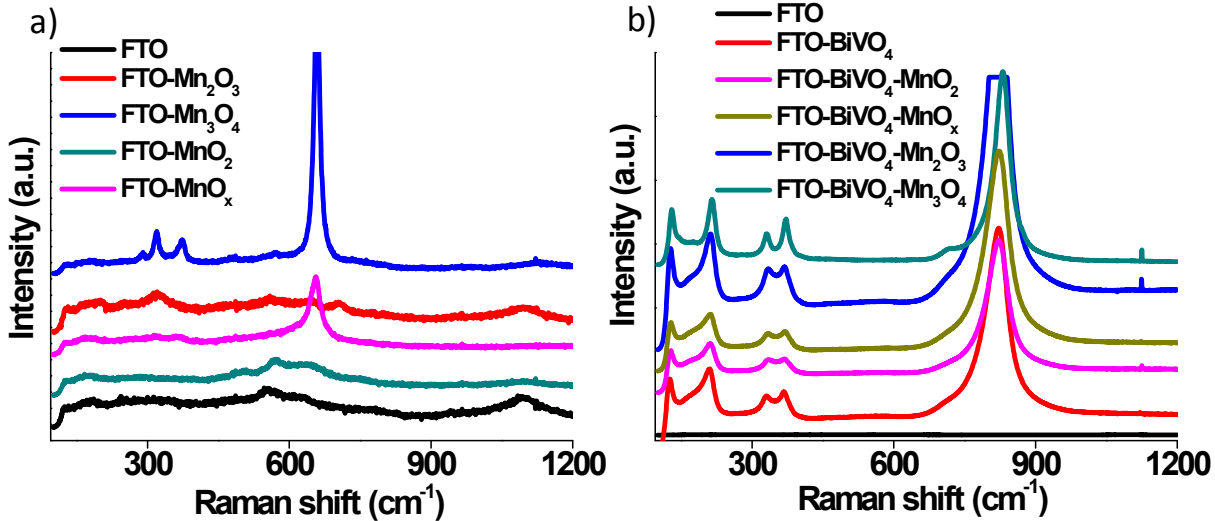


Fig S6. Raman analyses for a) deposited Manganese oxides on FTO b) deposited Manganese oxides on FTO-BiVO₄.

Note: Raman analyses (**Fig. S6a**) for MnO₂ shows weak peaks at 503, 570, 644 and 756 cm⁻¹, raman modes at 570 cm⁻¹ and 644 cm⁻¹ corresponds to the A_g breathing vibrations of MnO₆ octahedra in the structure.¹ Raman analysis of Mn₂O₃ (**Fig. S6a**) depicts peaks at 321, 559, 650 and 707 cm⁻¹ corresponds to the vibrational modes corresponding to out of plane symmetric and asymmetric vibrations of Mn-O-Mn species.² In the case of Mn₃O₄ (**Fig. S6a**) characteristic band is observed at 655 cm⁻¹ in addition to other vibration modes at 289, 321, 372, 483, 572 cm⁻¹. The band at 655 cm⁻¹ corresponds to A_{1g} mode of vibration of Mn-O breathing vibrations of Mn²⁺ in tetrahedral coordination which supports the presence of Mn₃O₄ phase of Mn oxide.³ Mn₃O₄ is obtained by heat treatment at 600 °C from the MnO₂. The heat treatment helps in the intercalation of Mn²⁺ ions in the tetrahedral sites and results in phase transformation of MnO₂ to Mn₃O₄.⁴ Whereas, the Raman spectra of MnO_x (**Fig. S6a**) shows vibration modes at 321, 650 and 707 cm⁻¹ which are matching with the peak both from the Mn₂O₃ and Mn₃O₄ and clearly signifies the mixed phase nature of the material i.e. a combination of Mn³⁺ and Mn⁴⁺ oxidation states. Typical vibrations corresponding to the BiVO₄ are observed at 129, 210, 330, 366, 702 and 820 cm⁻¹ as shown in **Fig. S6b**. Bands at 330 and 366 cm⁻¹ depict the asymmetric and symmetric formations of VO₄ tetrahedron. Raman bands centred at 702 and 820 cm⁻¹ indicate the two vibrational modes of V-O bonds. With addition of Mn oxides and annealing at different temperatures, shift in the peaks of electrodeposited BiVO₄ is observed due to the change in the

electronic environment by electrodeposition of the Mn oxides.⁵ The peaks corresponding to different Mn oxides on the BiVO₄ were not observed clearly in **Fig. S6b** due to high intensity signals of BiVO₄ due to lesser deposition of respective Mn oxides.

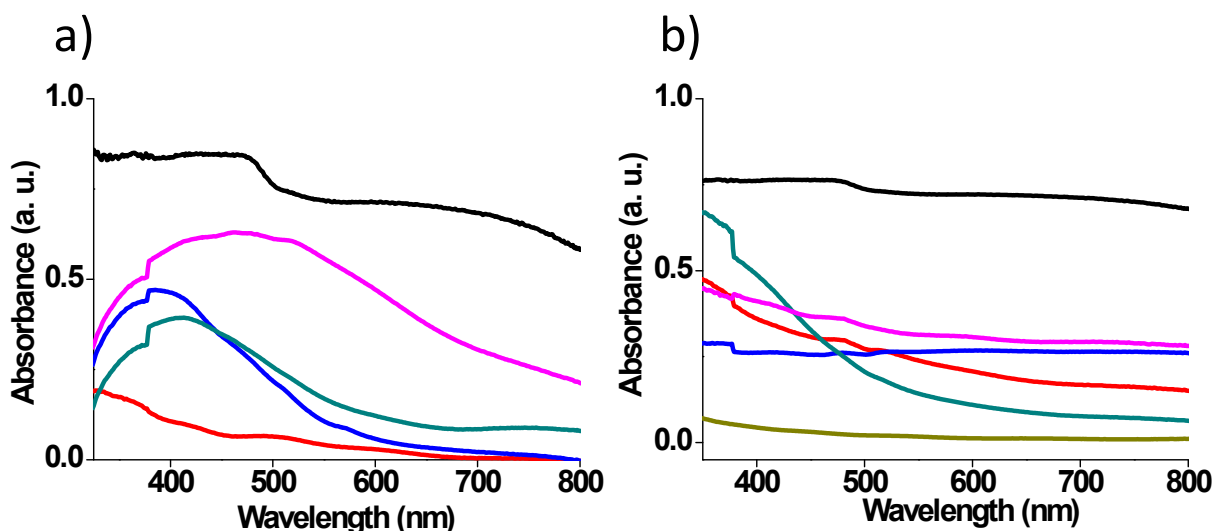


Fig. S7. a) UV-vis absorption spectra of electrodeposited Mn oxides, FTO-BiVO₄ (black line), FTO-MnO₂ (green line), FTO-MnO_x (pink line), FTO-Mn₂O₃ (red line), FTO-Mn₃O₄ (blue line) b) UV-vis absorption spectra of electrodeposited Mn oxides on FTO-BiVO₄ (black line), FTO-BiVO₄-MnO₂ (green), FTO-BiVO₄-MnO_x (pink), FTO-BiVO₄-Mn₂O₃ (red), FTO-BiVO₄-Mn₃O₄ (blue).

Note: FTO-MnO_x showed broad absorption edge highlighting the presence of mixture of oxides in its composition. FTO-MnO₂ shows broad absorption edge in the range of 411-560 nm owing to the possible d-d transitions in the lower t_{2g} and higher e_g energy levels in the ligand field of MnO₆ octahedra.⁶ FTO-Mn₂O₃ has shown absorption edges at 360, 423 and 512 nm. Absorption at 360 nm is the characteristic of the presence of Mn⁺³ ions in the sample.⁷ Broad absorption peaks are observed at 417, 510 and 571 nm for FTO-Mn₃O₄ relating to the Jahn–Teller (J–T) distorted d-d transitions possible in the structure and band gap plots are shown in **Fig. S7a**.⁸ The absorption spectra of deposition of Mn oxides on the FTO-BiVO₄ were recorded (**Fig. S7b**). The absorption spectra of the films showed broad absorption range of 443-668 nm and 452-648 nm in the case of FTO-BiVO₄-MnO_x and FTO-BiVO₄-Mn₂O₃ respectively. This indicated that the photoanodes are suitable for visible light absorption and have the required band gaps of 2.5-2.6 eV as shown in **Fig. S7**. A sharp fall in the absorbance was obtained in the range of 400-518 nm for FTO-BiVO₄-MnO₂ corresponding to the band gap of 2.49 eV. Band gap of 2.25 eV was

obtained for FTO-BiVO₄-Mn₃O₄ owing to the weak absorption edges at 413, 484 and 604 nm. Band gap plots have been shown on **Figure S8, S9** and the values are tabulated in **Table S1**. Band gaps have been calculated using the Tauc plots using the relation:

$$\alpha h\nu = A (h\nu - E_g)^n$$

where, α is the absorption coefficient (cm⁻¹), $h\nu$ is the photon energy (eV), A is the constant, E_g is the band gap (eV) and n determines the type of transition and has value $\frac{1}{2}$, $\frac{3}{2}$, 2 and 3 for direct allowed, direct forbidden transition, indirect allowed and indirect forbidden transition, respectively.

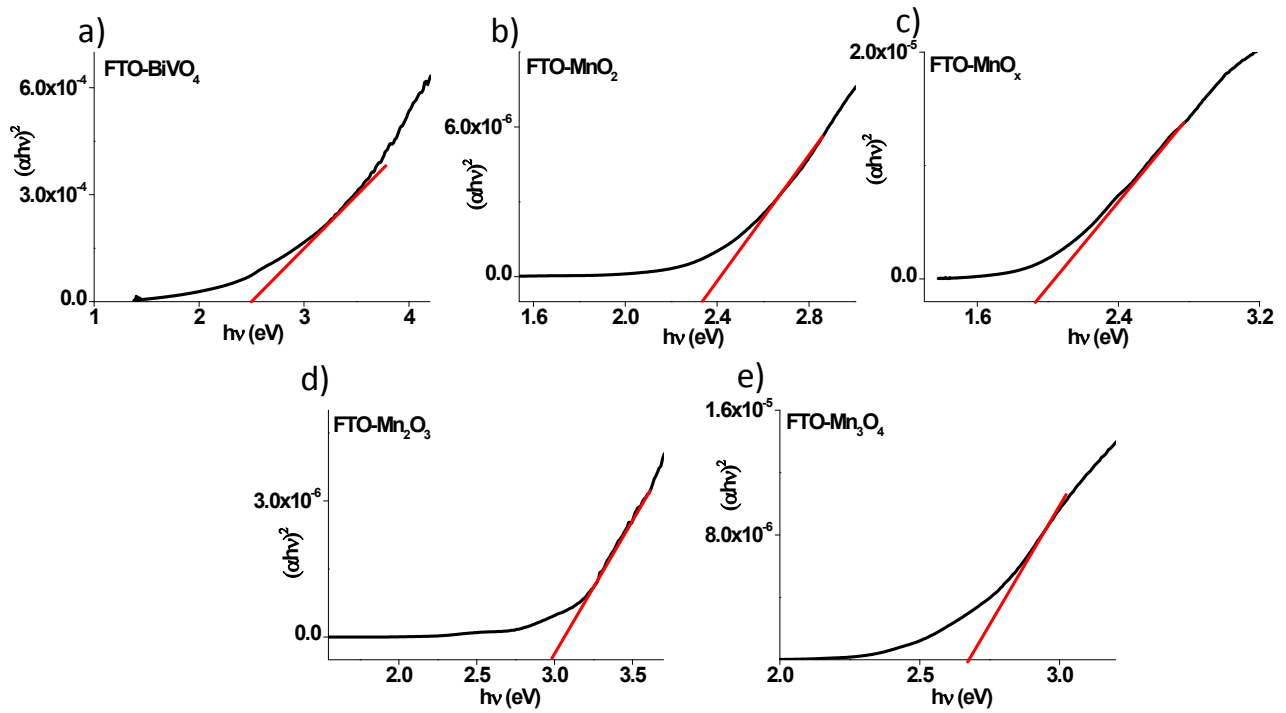


Fig. S8. Band gap plots from Tauc relations are shown for a) FTO-BiVO₄ b) FTO-MnO₂ c) FTO-MnO_x d) FTO-Mn₂O₃ e) FTO-Mn₃O₄.

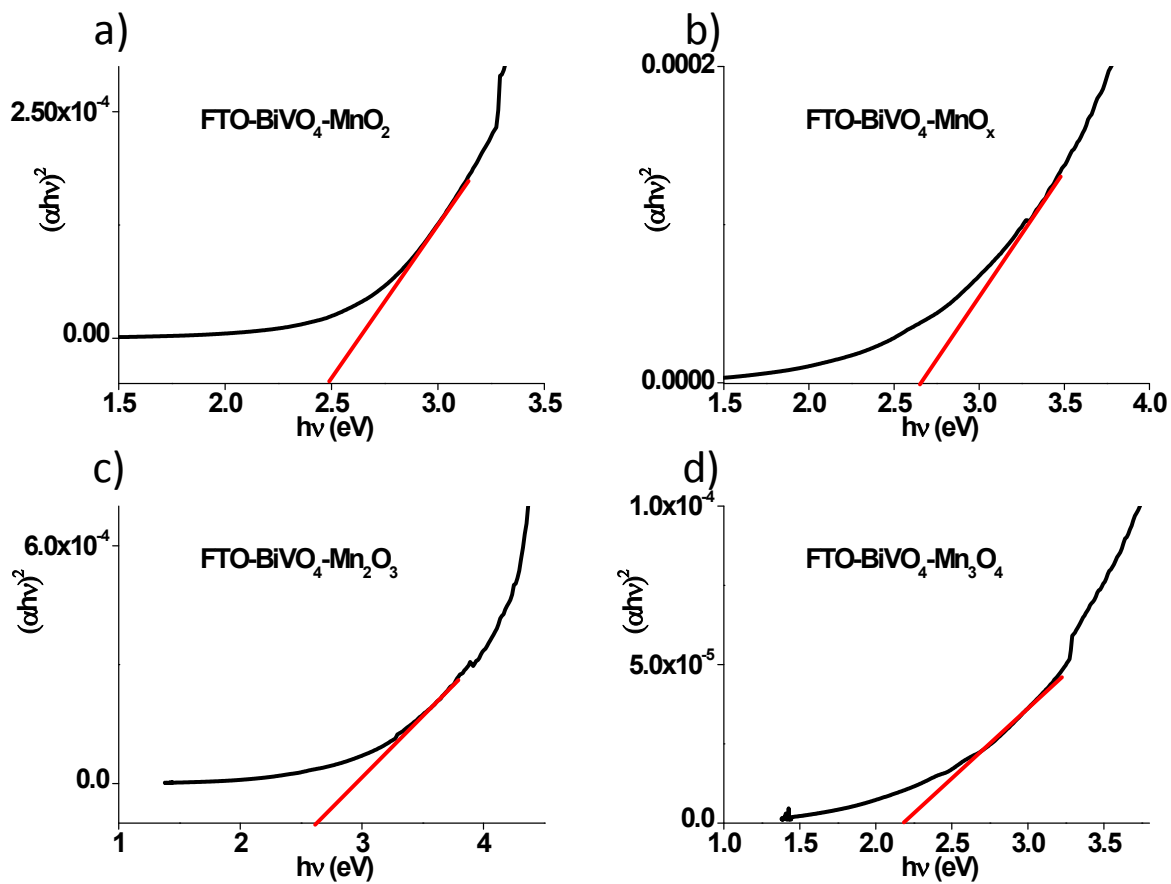


Fig. S9. Band gap plots from Tauc relations are shown for a) FTO-BiVO₄-MnO₂ b) FTO-BiVO₄-MnO_x c) FTO-BiVO₄-Mn₂O₃ d) FTO-BiVO₄-Mn₃O₄.

Table S1. Band gap values obtained from Tauc plot:

| Compound | Band Gaps from Tauc plots (eV) |
|---|---------------------------------------|
| FTO-BiVO₄ | 2.64 |
| FTO-MnO₂ | 2.34 |
| FTO-Mn₂O₃ | 2.99 |
| FTO-MnO_x | 1.87 |
| FTO-Mn₃O₄ | 2.63 |
| FTO-BiVO₄-MnO₂ | 2.49 |
| FTO-BiVO₄-Mn₂O₃ | 2.51 |
| FTO-BiVO₄-MnO_x | 2.65 |
| FTO-BiVO₄-Mn₃O₄ | 2.25 |

Table S2. XPS deconvoluted peaks for Mn and Bi summarised:

| Compound | Mn2p (eV) | | Bi4f (eV) | |
|---|-------------------------|-------------------------|-------------------------|-------------------------|
| | 2p_{3/2} | 2p_{1/2} | 4f_{7/2} | 4f_{5/2} |
| FTO-BiVO₄ | - | - | 158.58 | 163.84 |
| FTO-BiVO₄-MnO₂ | 642.90 | 654.43 | 159.07 | 164.33 |
| FTO-BiVO₄-MnO_x-before PEC | 641.52/644 | 653.42 | 158.61 | 163.96 |
| FTO-BiVO₄-MnO_x-after PEC | 641.52/643.45 | 654.16 | 159.12 | 164.40 |
| FTO-BiVO₄-Mn₂O₃ | 641.60 | 653.17 | 157.92 | 163.20 |
| FTO-BiVO₄-Mn₃O₄ | 639.03/641.98 | 653.12 | 158.64 | 163.93 |

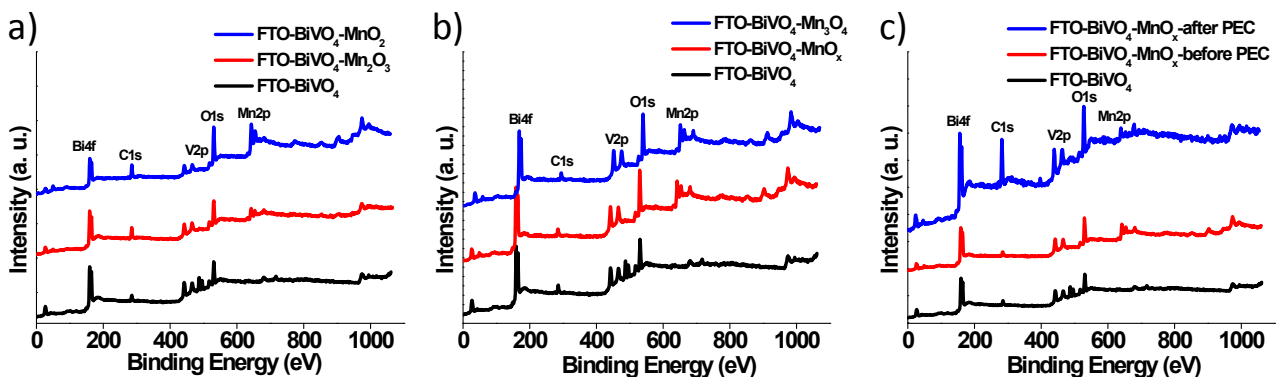


Fig. S10. X-ray photoelectron survey scan spectra for a) FTO-BiVO₄, FTO-BiVO₄-MnO₂ and FTO-BiVO₄-Mn₂O₃ b) FTO-BiVO₄, FTO-BiVO₄-MnO_x and FTO-BiVO₄-Mn₃O₄ c) FTO-BiVO₄, FTO-BiVO₄-MnO_x before Photoelectrochemical water splitting (PEC) and FTO-BiVO₄-MnO_x after PEC.

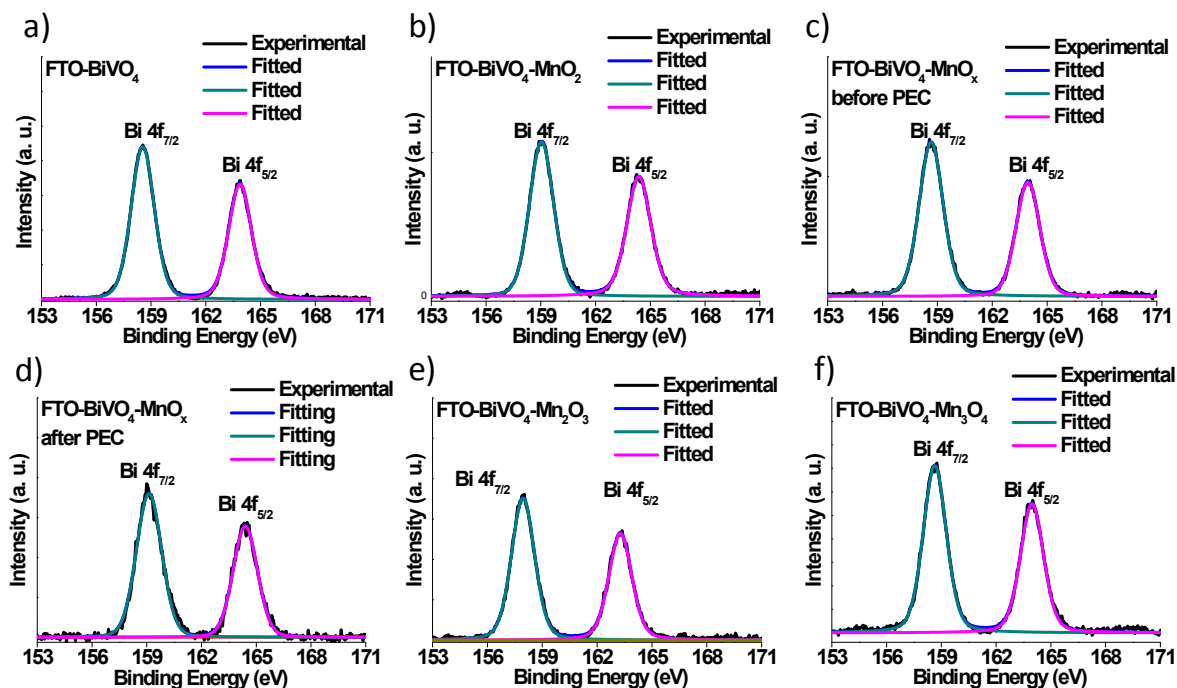


Fig. S11. Deconvoluted peaks of Bi 4f_{7/2} and Bi 4f_{5/2} for a) FTO-BiVO₄ b) FTO-BiVO₄-MnO₂ c) FTO-BiVO₄-MnO_x before Photoelectrochemical water splitting (PEC) d) FTO-BiVO₄-MnO_x after PEC e) FTO-BiVO₄-Mn₂O₃ f) FTO-BiVO₄-Mn₃O₄.

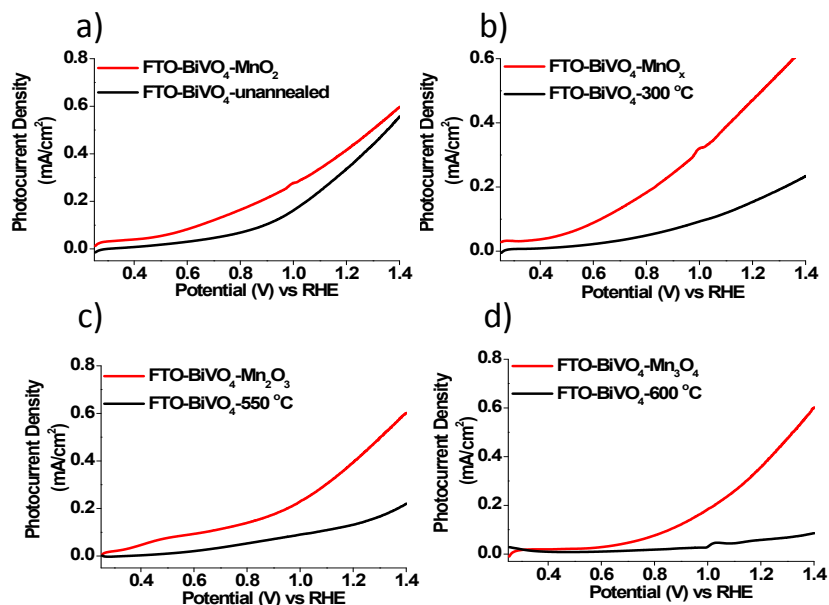


Fig. S12. Photocurrent density (J) vs Potential (V) vs RHE curves for full light illumination for a) FTO-BiVO₄-MnO₂ compared with unannealed BiVO₄ b) FTO-BiVO₄-MnO_x compared with BiVO₄ annealed at 300 °C c) FTO-BiVO₄-Mn₂O₃ compared with BiVO₄ annealed at 550 °C d) FTO-BiVO₄-Mn₃O₄ compared with BiVO₄ annealed at 600 °C under visible light illumination of 100 mW/cm² in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7).

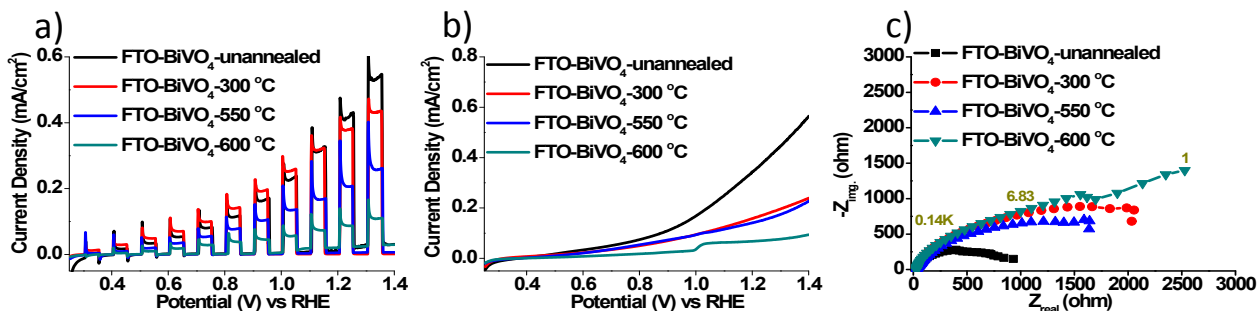


Fig. S13. a) Comparison of J-V curves for chopped light illumination for FTO-BiVO₄ unannealed with the FTO-BiVO₄ annealed at 300 °C, 550 °C and 600 °C b) Comparison of J-V curves for full light illumination for FTO-BiVO₄ unannealed with the FTO-BiVO₄ annealed at 300 °C, 550 °C and 600 °C c) Comparison of Nyquist plots of FTO-BiVO₄ unannealed with the FTO-BiVO₄ annealed at 300 °C, 550 °C and 600 °C, the numerical values (dark yellow font) in the plots represent the respective frequencies of the three data points below them, under visible light illumination of 100 mW/cm² in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7).

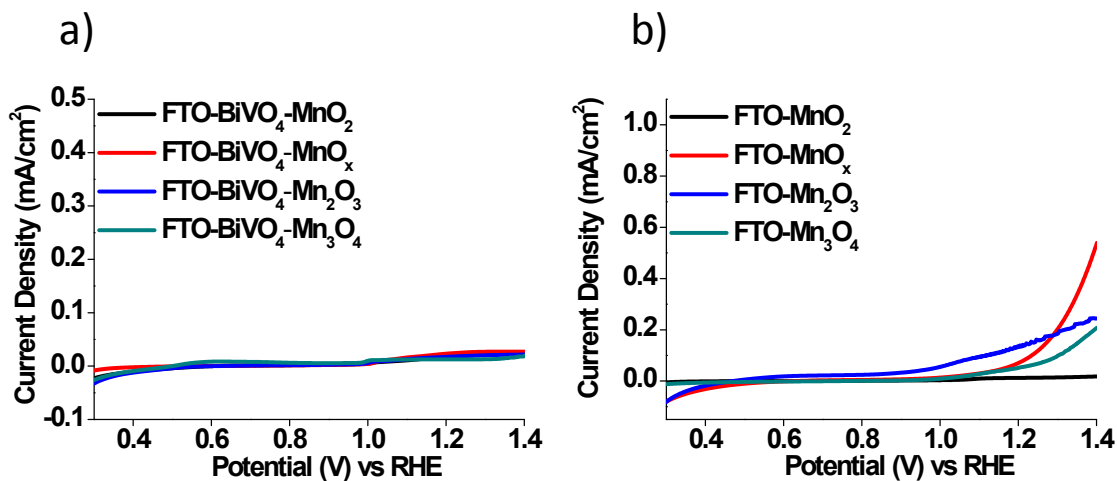


Fig. S14. Current density (J) vs Potential (V) vs RHE curves for a) FTO-BiVO₄-MnO₂, FTO-BiVO₄-MnO_x, FTO-BiVO₄-Mn₂O₃ and FTO-BiVO₄-Mn₃O₄ in dark in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7) b) in full light illumination for FTO-MnO₂, FTO-MnO_x, FTO-Mn₂O₃ and FTO-Mn₃O₄ in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7).

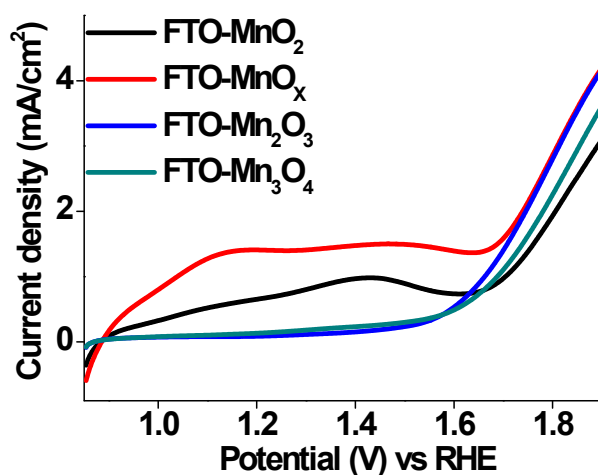


Fig. S15. Comparison of Current Density (J) as a function of potential (V) vs RHE of FTO-MnO₂, FTO-MnO_x, FTO-Mn₂O₃, FTO-Mn₃O₄ in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7).

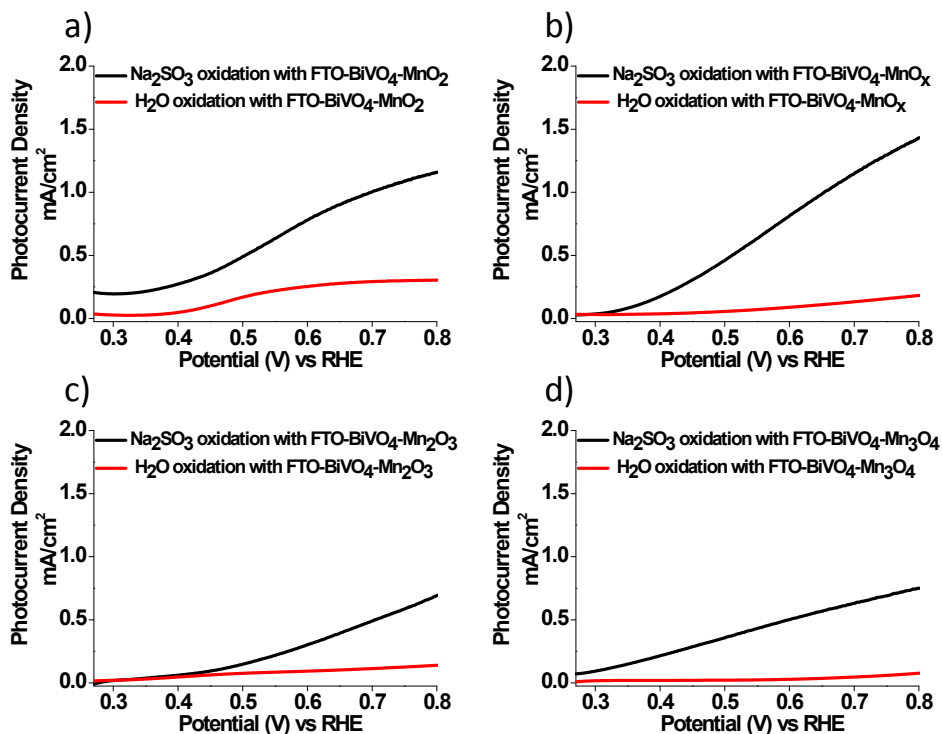


Fig. S16. Photocurrent density (J) vs Potential (V) (vs RHE) plots for Na₂SO₃ vs H₂O oxidation for a) FTO-BiVO₄-MnO₂ b) FTO-BiVO₄-MnO_x c) FTO-BiVO₄-Mn₂O₃ d) FTO-BiVO₄-Mn₃O₄ under visible light illumination of 100 mW/cm² in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7).

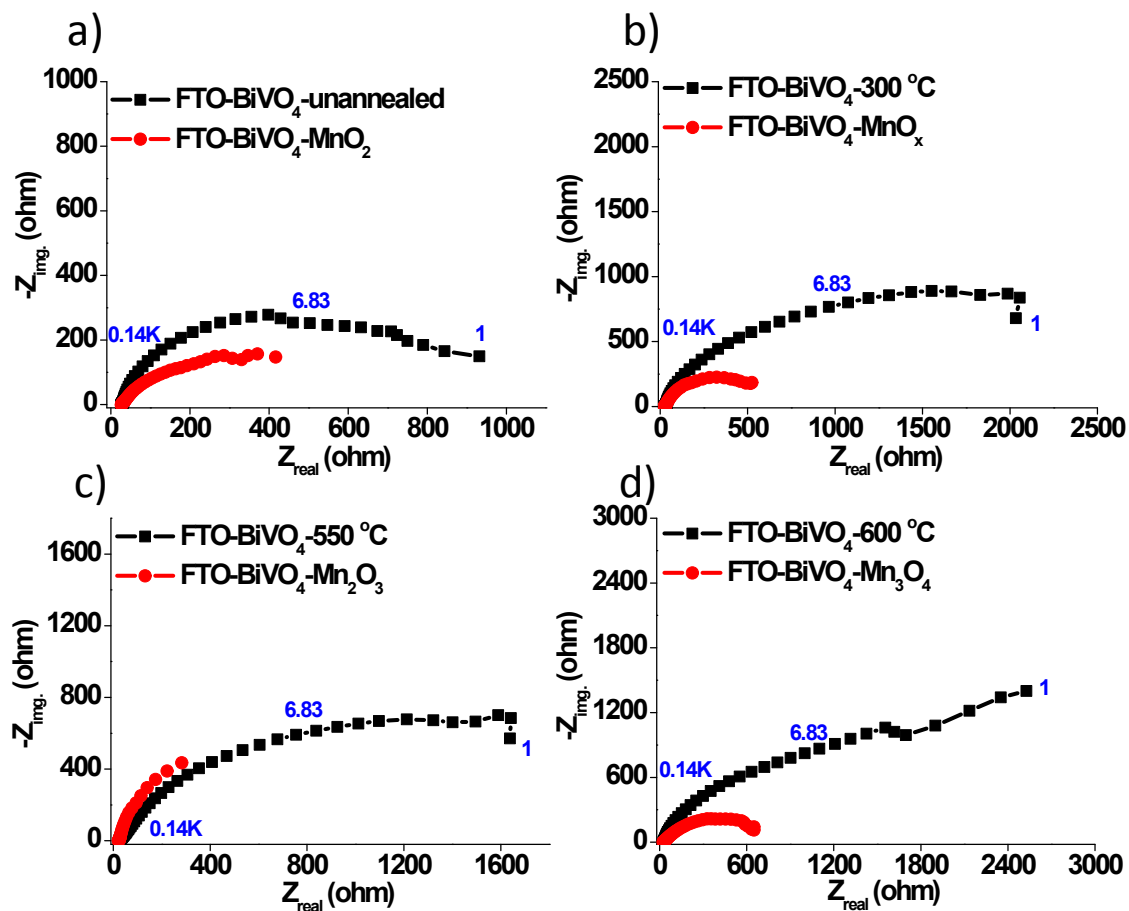


Fig. S17. Nyquist plots in full light illumination for a) FTO-BiVO₄-MnO₂ compared with unannealed BiVO₄ b) FTO-BiVO₄-MnO_x compared with BiVO₄ annealed at 300 °C c) FTO-BiVO₄-Mn₂O₃ compared with BiVO₄ annealed at 550 °C d) FTO-BiVO₄-Mn₃O₄ compared with BiVO₄ annealed at 600 °C under visible light illumination of 100 mW/cm² in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7), the numerical values (blue font) in the plots represent the respective frequencies of the three data points above/below them.

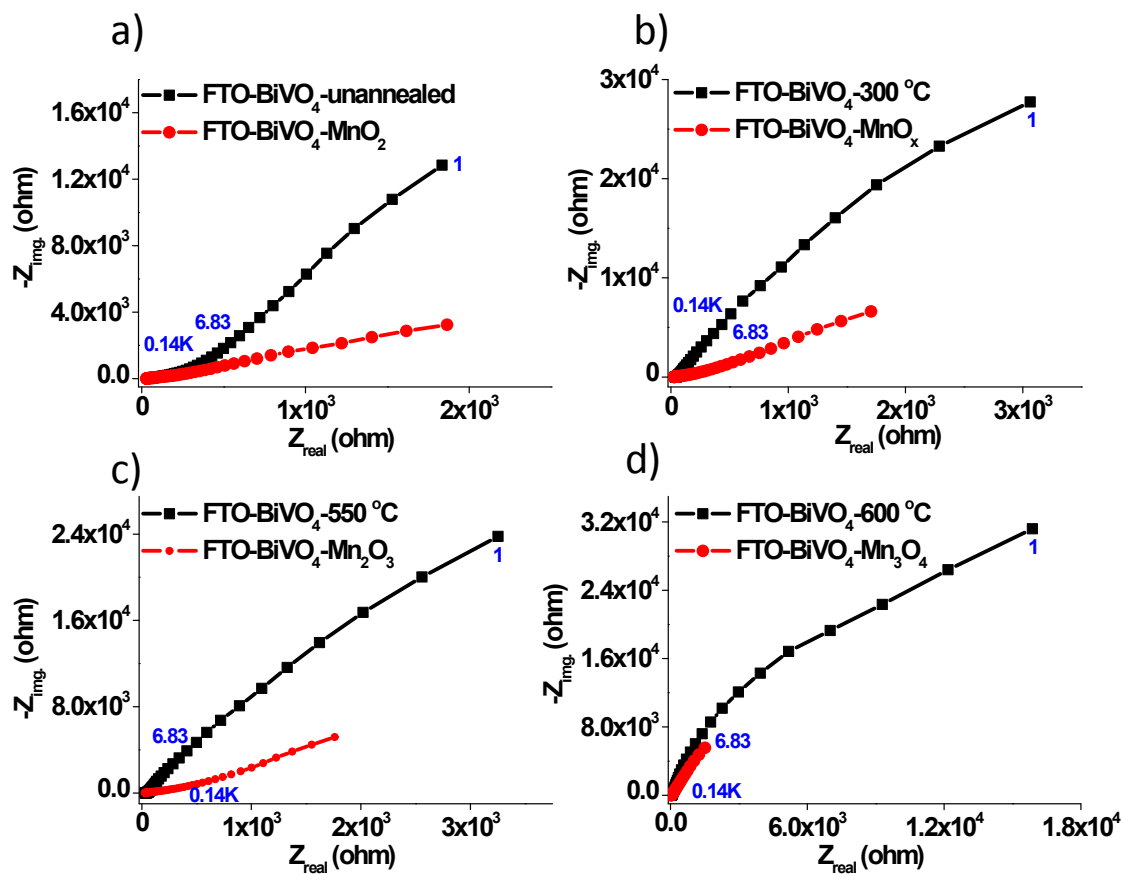


Fig. S18. Nyquist plots in dark for e) FTO-BiVO₄-MnO₂ compared with unannealed BiVO₄ f) FTO-BiVO₄-MnO_x compared with BiVO₄ annealed at 300 °C g) FTO-BiVO₄-Mn₂O₃ compared with BiVO₄ annealed at 550 °C h) FTO-BiVO₄-Mn₃O₄ compared with BiVO₄ annealed at 600 °C in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7), the numerical values (blue font) in the plots represent the respective frequencies of the three data points above/below them.

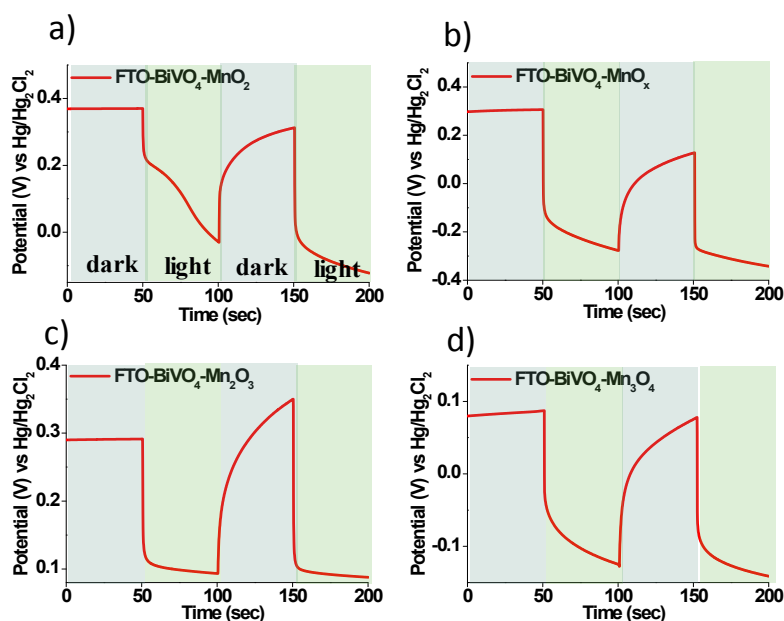


Fig. S19. Open circuit potential (ocp) vs time plots for consecutive light and dark illumination for c) FTO-BiVO₄-MnO₂ d) FTO-BiVO₄-MnO_x e) FTO-BiVO₄-Mn₂O₃ f) FTO-BiVO₄-Mn₃O₄ under visible light illumination of 100 mW/cm² in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7).

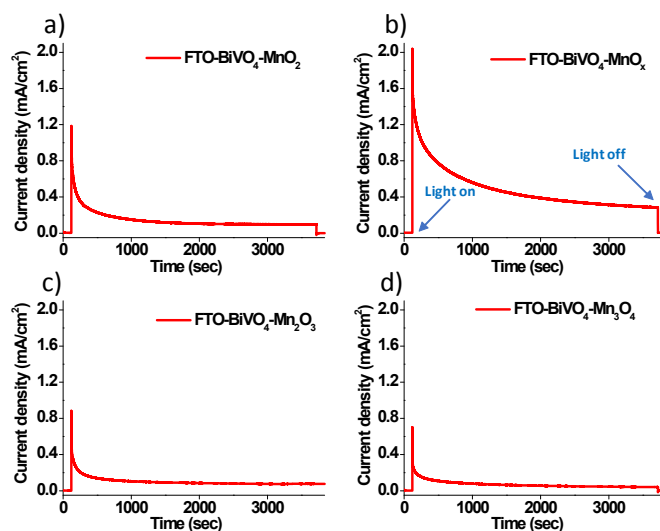


Fig. S20. Current Density (J) vs t plots showing stability of a) FTO-BiVO₄-MnO₂ b) FTO-BiVO₄-MnO_x c) FTO-BiVO₄-Mn₂O₃ d) FTO-BiVO₄-Mn₃O₄ under visible light illumination of 100 mW/cm² in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7). Light was switched on 120 sec after illumination and switched off 120 sec before the analysis time is over.

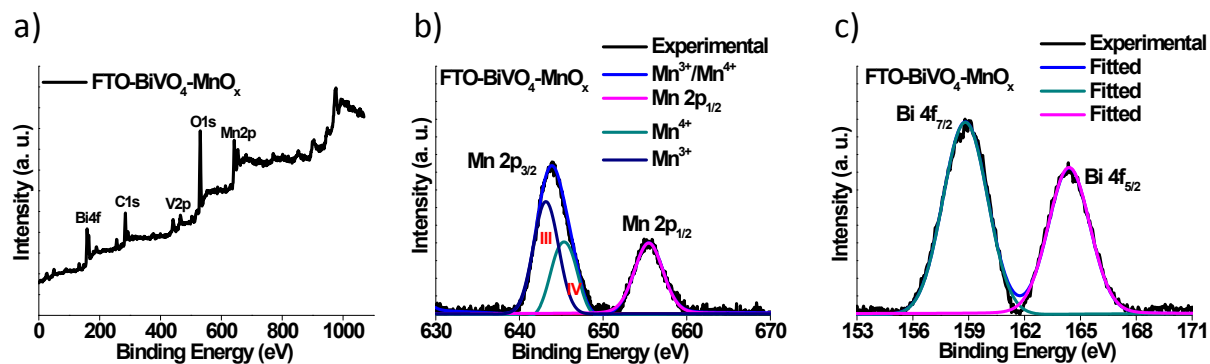


Fig. S21. X-ray photoelectron spectra for FTO-BiVO₄-MnO_x a) survey scan b) deconvoluted peaks of Mn 2p_{3/2} and Mn 2p_{1/2} c) deconvoluted peaks of Bi 4f_{7/2} and Bi 4f_{5/2}.

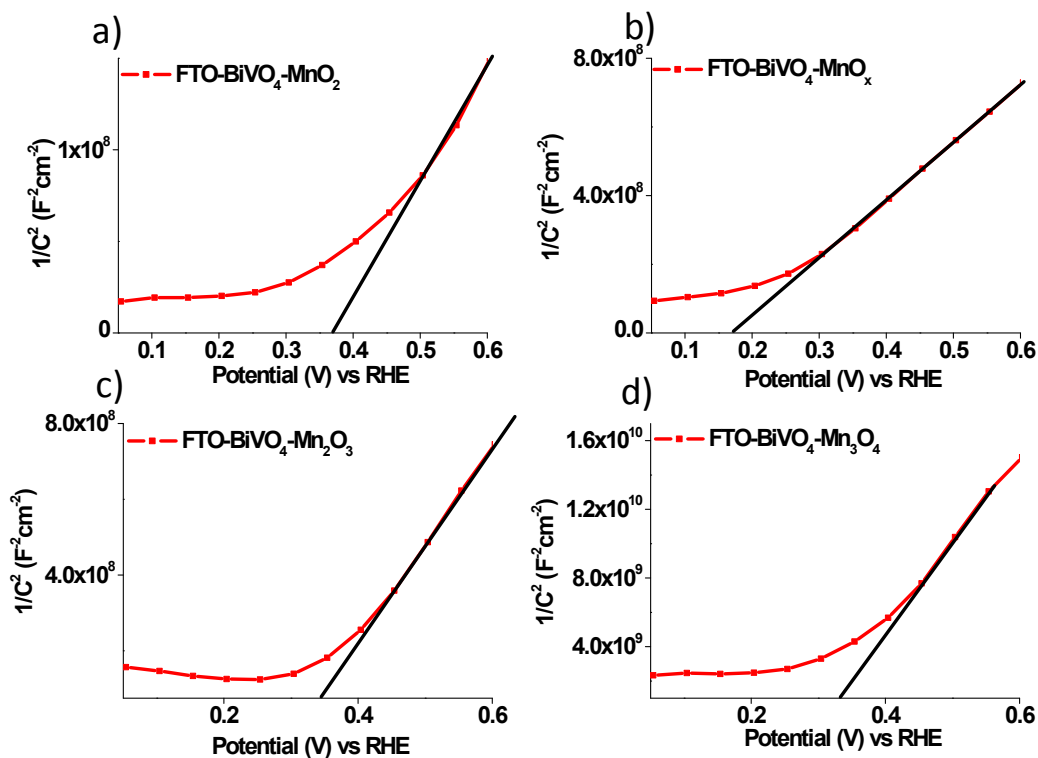


Fig. S22. Mott-Schottky plots for full light illumination for a) FTO-BiVO₄-MnO₂ b) FTO-BiVO₄-MnO_x c) FTO-BiVO₄-Mn₂O₃ d) FTO-BiVO₄-Mn₃O₄ under visible light illumination of 100 mW/cm² in 0.1 M Potassium phosphate (KPi) buffer solution (pH=7).

Table S3: Calculations for Flat band potential for photoanodes:

| Photoelectrode | Intercept (V) | Flat band potential (V_{fb}) |
|---|--------------------------------|---|
| FTO-BiVO₄-MnO₂ | -2.36 x 10⁸ | 0.34 |
| FTO-BiVO₄-MnO_x | -2.89 x 10⁸ | 0.14 |
| FTO-BiVO₄-Mn₂O₃ | -8.15 x 10⁸ | 0.32 |
| FTO-BiVO₄-Mn₃O₄ | -1.66 x 10¹⁰ | 0.30 |

References

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